TEXAS INSTRUMENTS
TMP708-Q1
JAJSCW5 – DECEMBER 2016

TMP708-Q1 車載用、抵抗によりプログラム可能なSOTパッケージの温度スイッチ

1 特長

- 車載アプリケーションに対応
- 下記内容でAEC-Q100認定済み：
  - デバイス温度グレード1: 動作時周囲温度範囲 –40°C～125°C
  - デバイスHBM ESD分類レベル3A
  - デバイスCDM ESD分類レベルC6
- スレッショルド精度:
  - ±0.5℃ (標準値)
  - ±3.5℃ (最大値、60℃～100℃)
- 1%の外付け抵抗により温度スレッショルドを設定
- 低い静止電流: 40µA (標準値)
- オープン・ドレイン、アクティブLOWの出力ステージ
- 10℃または30℃のヒステリシスをピンで選択可能
- V_{CC} = 0.8Vでリセット動作を規定
- 電源電圧範囲: 2.7V～5.5V
- パッケージ: 5ピンのSOT-23

2 アプリケーション

- コンピュータ (ラップトップおよびデスクトップ)
- サーバー
- 産業用および医療用機器
- ストレージ・エリア・ネットワーク
- 車載

3 概要

TMP708-Q1は完全に統合された、抵抗によりプログラム可能な温度スイッチで、1つの外付け抵抗だけで温度範囲全体に温度スレッショルドを設定できます。TMP708-Q1には、オープン・ドレイン、アクティブLOWの出力があり、2.7V～5.5Vの電源電圧範囲で動作します。

温度スレッショルド精度は標準で±0.5℃、最大値は±3.5℃です(60℃～100℃)。待機時消費電流は、標準で40µAです。ヒステリシスは、ピンによって10℃または30℃に設定できます。

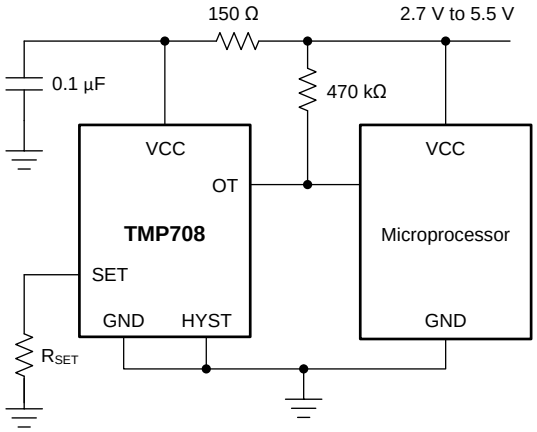
TMP708-Q1は5ピンのSOT-23パッケージで供給されます。

製品情報(1)

型番	パッケージ	本体サイズ(公称)
TMP708-Q1	SOT-23 (5)	2.90mm×1.60mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にあるパッケージ・オプションについての付録を参照してください。

代表的なアプリケーション



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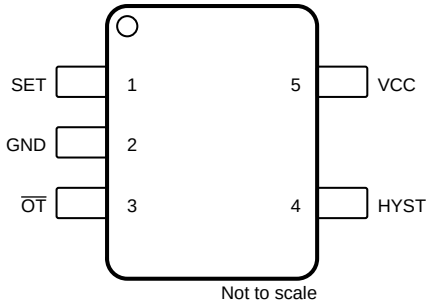
4 改訂履歴

日付	改訂内容	注
2016年12月	*	初版

5 Pin Configuration and Functions

DBV Package
5-Pin SOT-23
Top View



Not to scale

Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
GND	2	Analog power	Device ground
HYST	4	Digital input	Hysteresis selection. For 10°C, HYST = VCC; for 30°C, HYST = GND.
$\overline{OT}$	3	Digital output	Open-drain, active low output
SET	1	Analog input	Temperature set point. Connect an external 1% resistor between SET and GND.
VCC	5	Analog power	Power-supply voltage (2.7 V to 5.5 V)

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Voltage	Supply, VCC	–0.3	6	V
	Input, SET and HYST	–0.3	V_{CC} + 0.3	
	Output, OT	–0.3	6	
Current	Input		20	mA
	Output		20	
Temperature	Operating, T_A	–40	125	°C
	Junction, T_J		150	
	Storatge, T_{stg}	–65	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 (1)	±4000	V
		Charged-device model (CDM), per AEC Q100-011	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	2.7		5.5	V
T_A	Operating temperature	0		125	°C

6.4 Thermal Information

THERMAL METRIC (1)		TMP708-Q1 DBV (SOT-23) 5 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	217.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	86.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	44.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	4.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	43.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

at T_A = 0°C to 125°C and V_{CC} = 2.7 V to 5.5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
I_{CC}	Supply current	V_{CC} = 5 V		40	55	µA
		V_{CC} = 2.7 V		40	55	µA
TEMPERATURE						
T_E	Temperature error	T_A = 60°C to 100°C		±0.5	±3.5	°C
DIGITAL INPUT (HYST)						
V_{IH}	High-level input voltage		0.7 × V_{CC}			V
V_{IL}	Low-level input voltage				0.3 × V_{CC}	V
I_{lkg_in}	Input leakage current			1		µA
C_{IN}	Input capacitance			10		pF
ANALOG INPUT (SET)						
V_{IN}	Input voltage range		0		V_{CC}	V
DIGITAL OPEN-DRAIN OUTPUT ($\overline{OT}$)						
$I_{(OT\_SINK)}$	Output sink current	V_{OT} = 0.3 V	5	12		mA
$I_{lkg(OT)}$	Output leakage current	V_{OT} = V_{CC}		1		µA

6.6 Typical Characteristics

at T_A = 25°C and V_{CC} = 2.7 V to 5.5 V (unless otherwise noted)

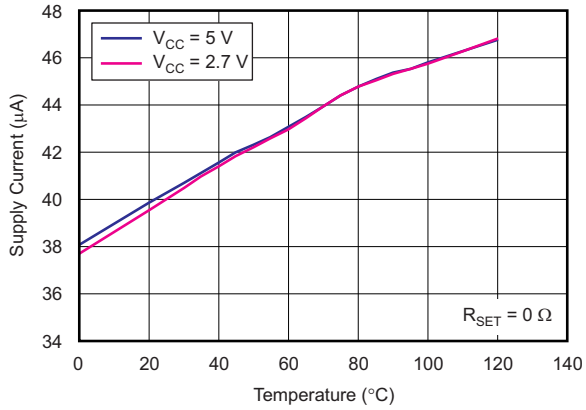


Figure 1. Supply Current vs Temperature

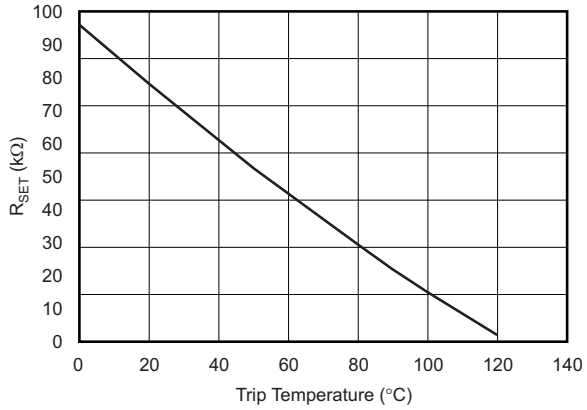


Figure 2. R_{SET} vs Trip Temperature

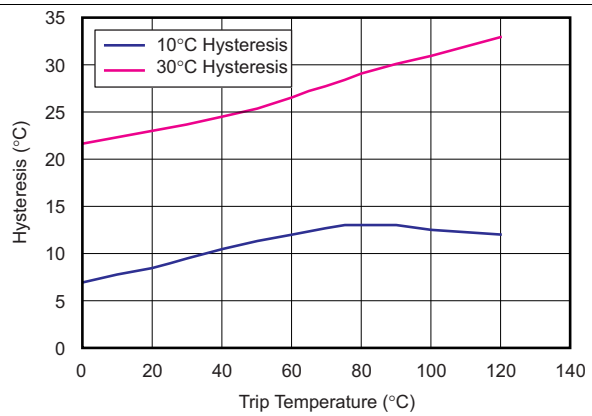


Figure 3. Hysteresis vs Trip Temperature

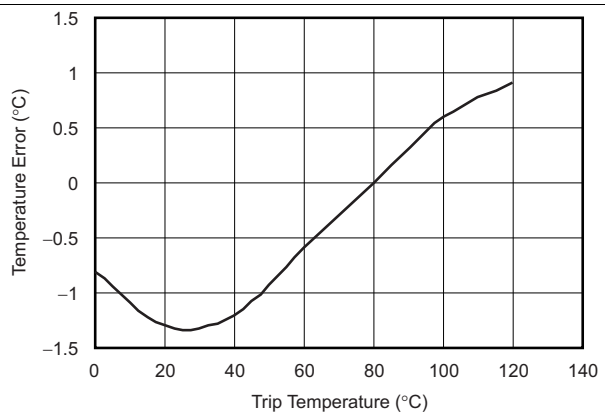


Figure 4. Temperature Error vs Trip Temperature

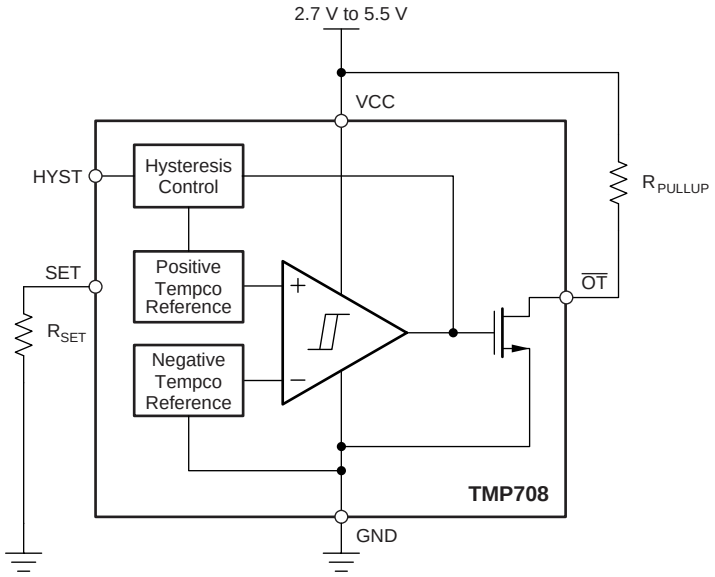
7 Detailed Description

7.1 Overview

The TMP708-Q1 is a fully-integrated, resistor-programmable temperature switch that incorporates two temperature-dependent voltage references and one comparator. One voltage reference exhibits a positive temperature coefficient (tempco), and the other voltage reference exhibits a negative tempco. The temperature at which both voltage references are equal determines the temperature trip point.

The Functional Block Diagram shows the comparator, the NFET open-drain device connected to the $\overline{OT}$ pin, the positive tempco reference using the external R_{SET} resistor, the negative tempco reference, and the hysteresis control. The voltage of the positive tempco reference is controlled by external resistor R_{SET}.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Temperature Switch

The TMP708-Q1 temperature threshold is programmable from 0°C to 125°C and is set by an external 1% resistor from the SET pin to the GND pin. The TMP708-Q1 has an open-drain, active-low output structure that easily interfaces with a microprocessor.

The TMP708-Q1 reaches the temperature trip point when the voltage from the positive tempco reference exceeds the voltage from the negative tempco reference. This difference causes the output of the comparator to switch from logic 0 to logic 1. The comparator output drives the gate of the NFET open-drain device, and pulls the voltage on the $\overline{OT}$ pin from logic 1 to logic 0 under these conditions; in other words, the output *trips*. Furthermore, the logic 1 output from the comparator causes the hysteresis control to increase the voltage of the positive tempco reference by an amount set by the logic setting on the HYST pin (10°C for logic 1 on the HYST pin; 30°C for logic 0 on the HYST pin). Increase the voltage of the positive tempco reference after the TMP708-Q1 trips to stop the TMP708-Q1 from untripping (voltage on the $\overline{OT}$ pin changing from logic 0 to logic 1) until the local temperature reduces by the amount set by the HYST pin. After the local temperature reduces, and the voltage from the positive tempco reference is less than the voltage from the negative tempco reference, the output of the comparator switches from logic 1 to logic 0. This condition causes the voltage on the $\overline{OT}$ pin to change from logic 0 to logic 1 (device untrips).

7.3.2 Hysteresis Input

The HYST pin is a digital input that allows the input hysteresis to be set at either 10°C (when HYST = VCC) or 30°C (when HYST = GND). The hysteresis function keeps the $\overline{OT}$ pin from oscillating when the temperature is near the threshold. Thus, always connect the HYST pin to either VCC or GND. Other input voltages on this pin can cause abnormal supply currents or a device malfunction.

7.3.3 Set-Point Resistor (R_{SET})

Set the temperature threshold by connecting R_{SET} from the SET pin to GND. The value of R_{SET} is determined using either Figure 2 or Equation 1:

$$R_{SET}\ (k\Omega) = 0.0012T^2 - 0.9308T + 96.147 \quad (1)$$

where

- T = temperature threshold in degrees Celsius.

7.4 Device Functional Modes

The TMP708-Q1 device has a single functional mode. Normal operation for the TMP708-Q1 device occurs when the power-supply voltage applied across the VCC and GND pins is within the specified operating range of 2.7 V to 5.5 V.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TMP708-Q1 device is simple to configure. The only external components that the device requires are a bypass capacitor and pullup resistor. Power-supply bypassing is strongly recommended. Use a 0.1-µF capacitor placed as close as possible to the VCC supply pin. To minimize the internal power dissipation of the TMP708-Q1 family of devices, use a pullup resistor value greater than 10 kΩ from the $\overline{OT}$ pin to the VCC pin. See the *Hysteresis Input* section for hysteresis configuration, and the *Set-Point Resistor (R_{SET})* section for configuring the temperature threshold.

8.2 Typical Application

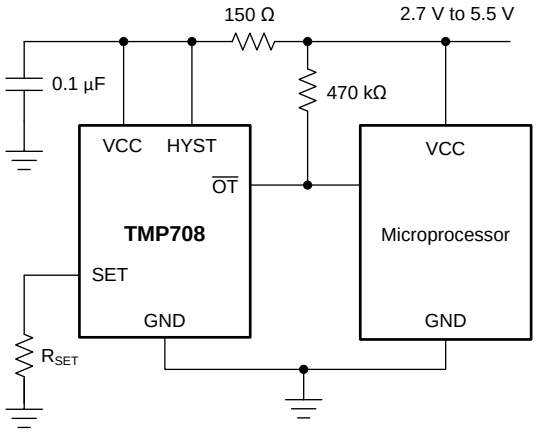


Figure 5. Overtemperature Protection for a 60°C Trip Point

8.2.1 Design Requirements

For this design example, a 2.7-V to 5.5-V power supply, 60°C trip point, and 10°C hysteresis are used.

Typical Application (continued)

8.2.2 Detailed Design Procedure

Connect the HYST pin to VCC for 10°C hysteresis. For a 60°C temperature threshold, see the *Set-Point Resistor (R_{SET})* section to compute an ideal R_{SET} resistor value of 44.619 kΩ. Select the closest standard value resistor available; in this case, 44.2 kΩ. Use a 10-kΩ pullup resistor from the $\overline{OT}$ pin to the VCC pin. To minimize power, a larger-value pullup resistor can be used, but must not exceed 470 kΩ. Place a 0.1-μF bypass capacitor close to the TMP708-Q1 device in order to reduce noise coupled from the power supply.

8.2.3 Application Curves

Figure 6 shows an example of the hysteresis feature. The HYST pin is connected to VCC, so the TMP708-Q1 device is configured for 10°C of hysteresis. The device is configured for a 60°C trip temperature by the R_{SET} resistor value; therefore, the $\overline{OT}$ output asserts low when the 60°C threshold is exceeded. The $\overline{OT}$ output remains asserted low until the sensor reaches 50°C.

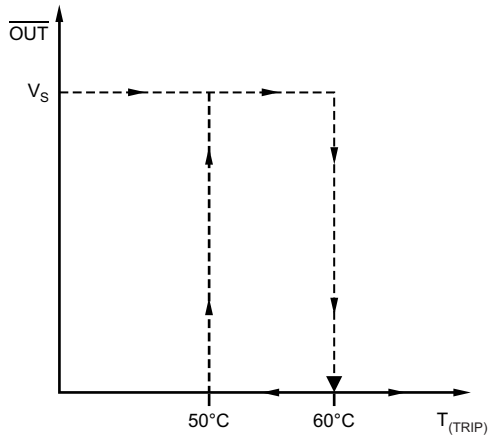


Figure 6. TMP708-Q1 Hysteresis Function

9 Power Supply Recommendations

The TMP708-Q1 low supply current and supply range allow this device to be powered from many sources. Any significant noise on the VCC pin can result in a trip-point error. Minimize this noise by low-pass filtering the device supply (V_{CC}) using a 150-Ω resistor and a 0.1-μF capacitor.

10 Layout

10.1 Layout Guidelines

The TMP708-Q1 is extremely simple to lay out. Figure 7 shows the recommended board layout.

10.2 Layout Example

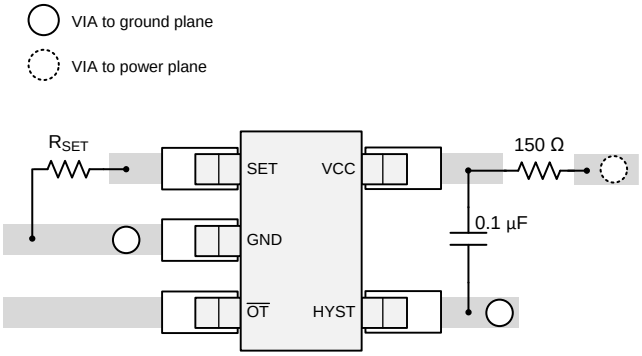


Figure 7. Recommended Layout

10.3 Thermal Considerations

The TMP708-Q1 quiescent current is typically 40 μA. The device dissipates negligible power when the output drives a high-impedance load. Thus, the die temperature is the same as the package temperature. In order to maintain accurate temperature monitoring, provide a good thermal contact between the TMP708-Q1 package and the device being monitored. The rise in die temperature as a result of self-heating is given by Equation 2:

$$\Delta T_J = P_{DISS} \times \theta_{JA} \quad (2)$$

where

- P_{DISS} = power dissipated by the device.
- θ_{JA} = package thermal resistance. Typical thermal resistance for SOT-23 package is 217.9°C/W.

To limit the effects of self-heating, keep the output current at a minimum level.

11 デバイスおよびドキュメントのサポート

11.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「*通知を受け取る*」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

11.2 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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設計サポート ***TIの設計サポート*** **役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。**

11.3 商標

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.4 静電気放電に関する注意事項

すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

11.5 用語集

SLYZ022 — *TI用語集*.

この用語集には、用語や略語の一覧および定義が記載されています。

12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TMP708AQDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	708Q	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF TMP708-Q1 :

- Catalog : TMP708

NOTE: Qualified Version Definitions:

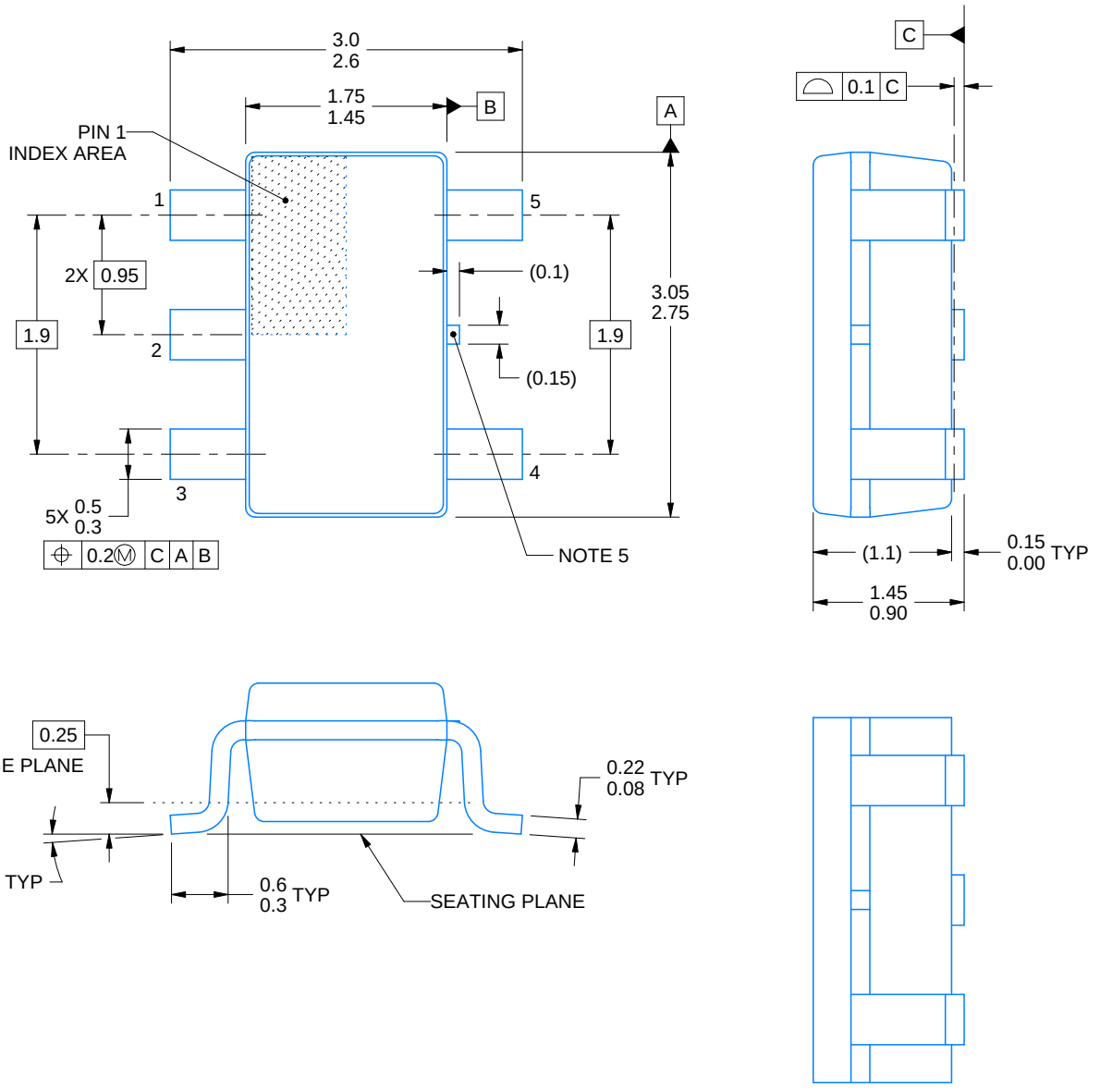
- Catalog - TI's standard catalog product

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

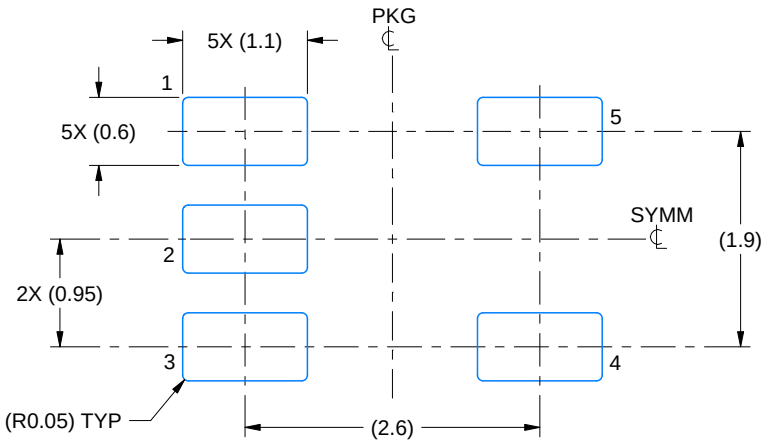


ALTERNATIVE PACKAGE SINGULATION VIEW

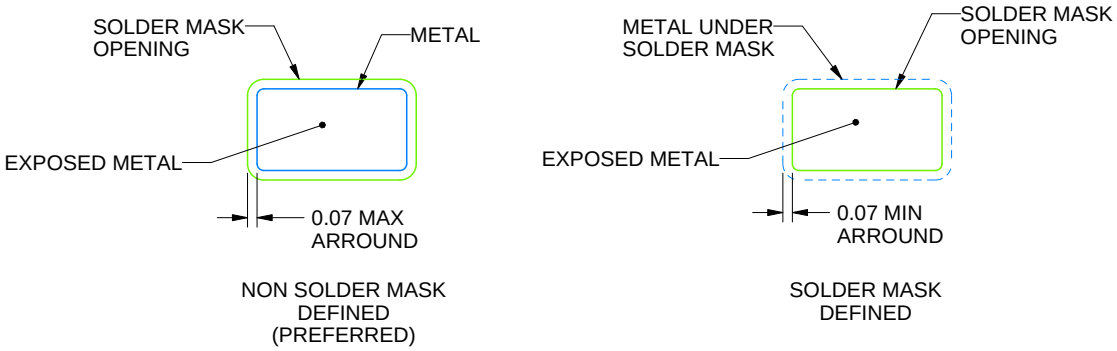
4214839/J 02/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

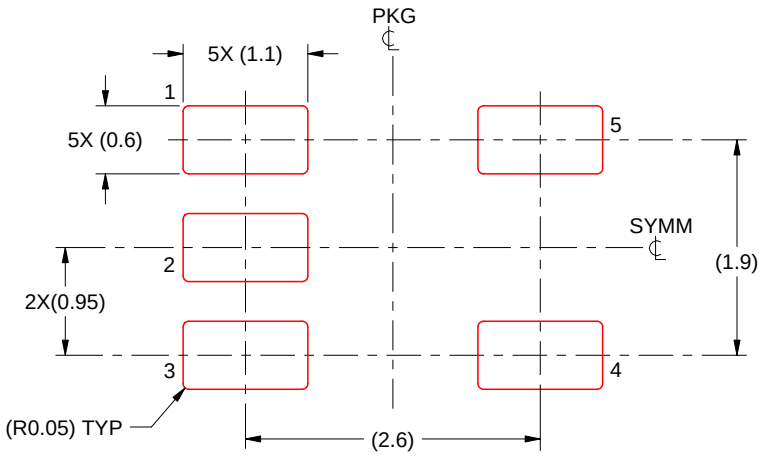


SOLDER MASK DETAILS

4214839/J 02/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/J 02/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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